

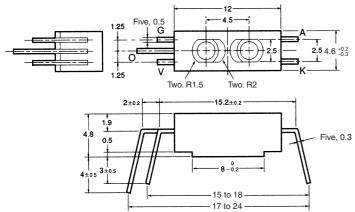
Photomicrosensor (Reflective) EE-SY310/-SY410



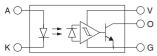
Be sure to read Precautions on page 24.

Dimensions

Note: All units are in millimeters unless otherwise indicated.



Internal Circuit



Terminal No.	Name
Α	Anode
K	Cathode
V	Power supply (Vcc)
0	Output (OUT)
G	Ground (GND)

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.2
3 < mm ≤ 6	±0.24
6 < mm ≤ 10	±0.29
10 < mm ≤ 18	±0.35
18 < mm ≤ 30	±0.42

■ Features

- Incorporates an IC chip with a built-in detector element and amplifier
- Incorporates a detector element with a built-in temperature compensation circuit.
- Compact reflective model with a molded housing.
- A wide supply voltage range: 4.5 to 16 VDC
- Directly connects with C-MOS and TTL.
- Dark ON model (EE-SY310)
- Light ON model (EE-SY410)
- Recommended sensing distance = 5.0 mm

■ Absolute Maximum Ratings (Ta = 25°C)

Ite	Symbol	Rated value	
Emitter	Forward current	I _F	50 mA (see note 1)
	Reverse voltage	V_R	4 V
	Pulse forward current	I _{FP}	1 A (see note 2)
Detector	Power supply voltage	V _{cc}	16 V
	Output voltage	V_{OUT}	28 V
	Output current	I _{OUT}	16 mA
	Permissible output dissipation	P _{OUT}	250 mW (see note 1)
Ambient tempera-	Operating	Topr	–40°C to 75°C
ture	Storage	Tstg	–40°C to 85°C
Soldering temperature		Tsol	260°C (see note 3)

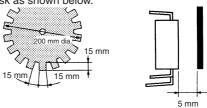
- **Note: 1.** Refer to the temperature rating chart if the ambient temperature exceeds 25°C.
 - 2. The pulse width is 10 μs maximum with a frequency of 100 Hz.
 - 3. Complete soldering within 10 seconds.

■ Electrical and Optical Characteristics (Ta = 25°C)

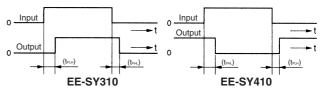
Item		Symbol Value		Condition	
Emitter	Forward voltage	V_{F}	1.2 V typ., 1.5 V max.	I _F = 20 mA	
	Reverse current	I _R	0.01 μA typ., 10 μA max.	V _R = 4 V	
	Peak emission wavelength	λ_{P}	920 nm typ.	I _F = 20 mA	
High-level output vo	Low-level output voltage	V _{OL}	0.12 V typ., 0.4 V max.	Vcc = 4.5 to 16 V, I _{OL} = 16 mA, without incident light (EE-SY310), with incident light (EE-SY410) (see notes 1 and 2)	
	High-level output voltage	V _{OH}	15 V min.	Vcc = 16 V, $R_L = 1 \text{ k}\Omega$, with incident light (EE-SY310), without incident ligh (EE-SY410) (see notes 1 and 2)	
	Current consumption	I _{cc}	3.2 mA typ., 10 mA max.	Vcc = 16 V	
	Peak spectral sensitivity wavelength	λ_{P}	870 nm typ.	V _{CC} = 4.5 to 16 V	
LED curre	ent when output is OFF	I _{FT}	6 mA typ., 15 mA max.	V _{CC} = 4.5 to 16 V	
LED curre	ent when output is ON				
Hysteresis	S	ΔΗ	17% typ.	V _{CC} = 4.5 to 16 V	
Response	frequency	f	50 Hz min.	$V_{CC} = 4.5 \text{ to } 16 \text{ V}, I_F = 15 \text{ mA}, I_{OL} = 16 \text{ mA}$	
Response	delay time	t _{PLH} (t _{PHL})	3 μs typ.	$V_{CC} = 4.5 \text{ to } 16 \text{ V}, I_F = 15 \text{ mA}, I_{OL} = 16 \text{ mA}$	
Response	delay time	t _{PHL} (t _{PLH})	20 μs typ.	$V_{CC} = 4.5 \text{ to } 16 \text{ V}, I_F = 15 \text{ mA}, I_{OL} = 16 \text{ mA}$	

Note: 1. With incident light" denotes the condition whereby the light reflected by white paper with a reflection factor of 90% at a sensing distance of 5 mm is received by the photo IC when the forward current (IF) of the LED is 20 mA.

- 2. Sensing object: White paper with a reflection factor of 90% at a sensing distance of 5 mm.
- 3. Hysteresis denotes the difference in forward LED current value, expressed in percentage, calculated from the respective forward LED currents when the photo IC is turned from ON to OFF and when the photo IC is turned from OFF to ON.
- 4. The value of the response frequency is measured by rotating the disk as shown below.



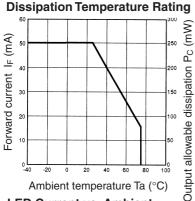
5. The following illustrations show the definition of response delay time. The value in the parentheses applies to the EE-SY410.



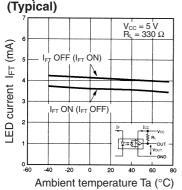
■ Engineering Data

Note: The values in the parentheses apply to the EE-SY410.

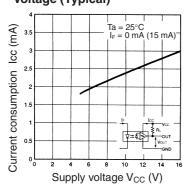
Forward Current vs. Collector



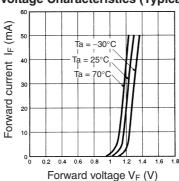
Ambient temperature Ta (°C) **LED Current vs. Ambient Temperature Characteristics**



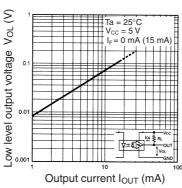
Current Consumption vs. Supply Voltage (Typical)



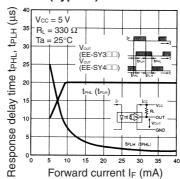
Forward Current vs. Forward Voltage Characteristics (Typical)



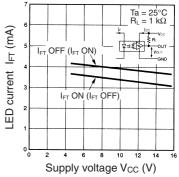
Low-level Output Voltage vs. Output Current (Typical)



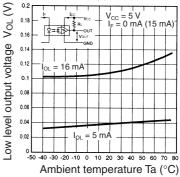
Response Delay Time vs. Forward Current (Typical)



LED Current vs. Supply Voltage (Typical)



Low-level Output Voltage vs. **Ambient Temperature Characteristics (Typical)**



Sensing Position Characteristics (Typical)

